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FDC658P Rev.C

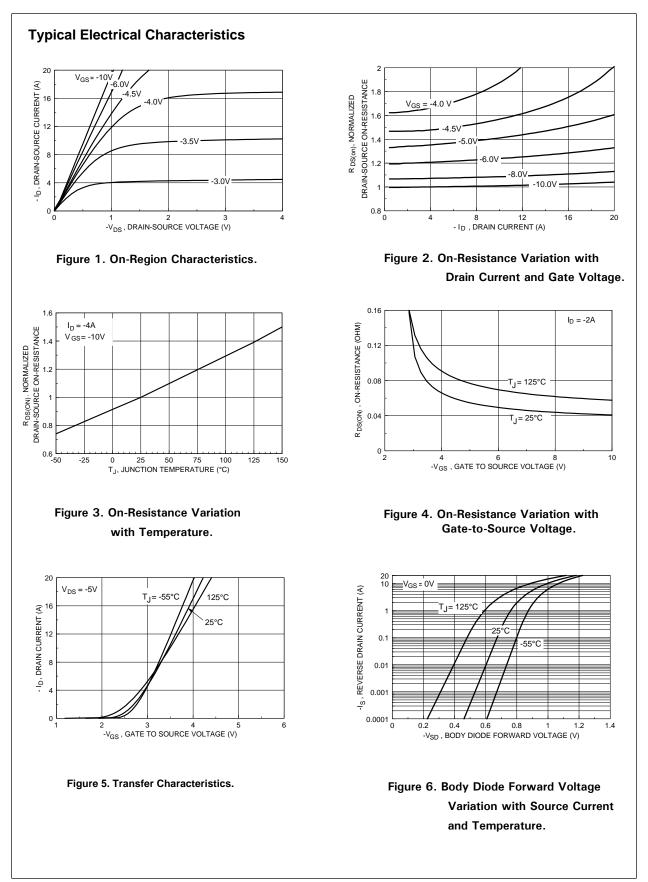
Symbol	Parameter	Conditions		Min	Тур	Max	Units
OFF CHAR	ACTERISTICS	•					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \ \mu\text{A}$		-30			V
$\Delta BV_{DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient	$I_{\rm D}$ = -250 µA, Referenced to 25 °C			-22		mV/ºC
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 V, V_{GS} = 0 V$				-1	μA
			T _J = 55 °C			-10	μA
I _{GSSF}	Gate - Body Leakage, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$				100	nA
	Gate - Body Leakage, Reverse	$V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$				-100	nA
ON CHARA	CTERISTICS (Note 2)						
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1	-1.7	-3	V
$\Delta V_{GS(th)} / \Delta T_J$	Gate Threshold VoltageTemp.Coefficient	$I_{\rm D}$ = -250 µA, Referenced to 25 °C			4.1		mV/°C
R _{DS(ON)}	Static Drain-Source On-Resistance	$V_{GS} = -10 \text{ V}, I_{D} = -4.0 \text{ A}$			0.041	0.05	Ω
			T _J = 125 °C		0.058	0.08	
		$V_{GS} = -4.5 \text{ V}, \ \text{I}_{D} = -3.4 \text{ A}$			0.06	0.075	
I _{D(on)}	On-State Drain Current	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$		-20			Α
9 _{FS}	Forward Transconductance	$V_{DS} = -5V, I_{D} = -4 A$			9		S
DYNAMIC C	HARACTERISTICS						
C _{iss}	Input Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz			750		pF
C _{oss}	Output Capacitance				220		pF
C _{rss}	Reverse Transfer Capacitance				100		pF
SWITCHING	CHARACTERISTICS (Note 2)						
t _{D(on)}	Turn - On Delay Time	$V_{DD} = -15 \text{ V}, \text{ I}_{D} = -1 \text{ A},$ $V_{GS} = -10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$			12	22	ns
t,	Turn - On Rise Time				14	25	ns
t _{D(off)}	Turn - Off Delay Time				24	38	ns
t,	Turn - Off Fall Time				16	27	ns
Q _g	Total Gate Charge	$V_{DS} = -15 V, I_{D} = -4.0 A,$			8	12	nC
Q _{qs}	Gate-Source Charge	$V_{GS} = -5 V$			1.8		nC
Q _{gd}	Gate-Drain Charge				3		nC
DRAIN-SOU	RCE DIODE CHARACTERISTICS				•		
l _s	Continuous Source Diode Current				-1.3	Α	
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = -1.3 A$ (Note 2)			-0.76	-1.2	V

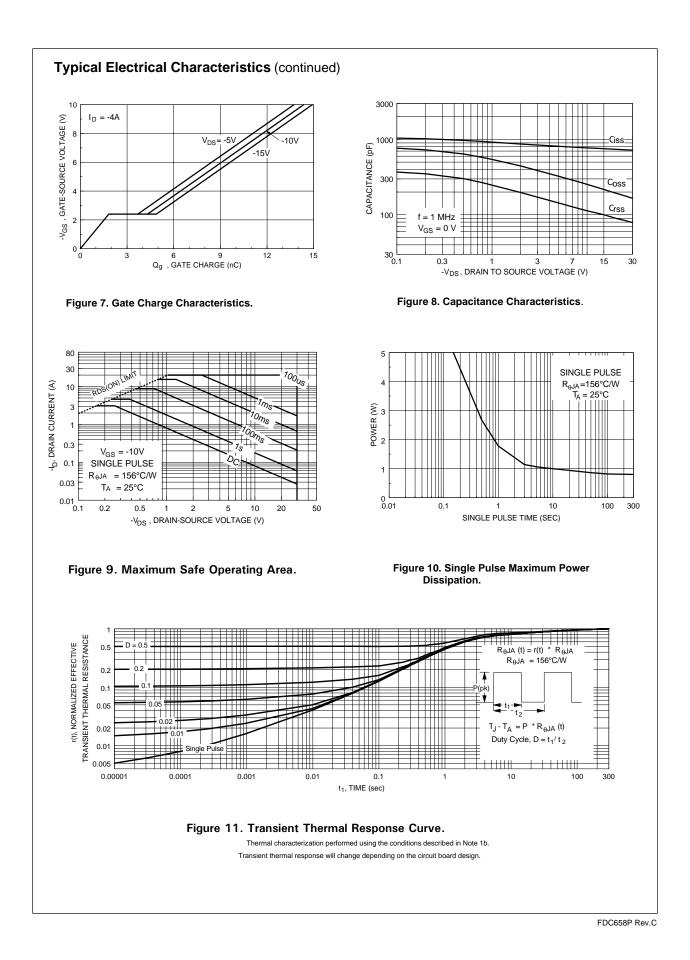
1. R_{guh} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{guc} is guaranteed by design while R_{gch} is determined by the user's board design.

a. 78°C/W when mounted on a 1 in² pad of 2oz Cu on FR-4 board.

b. 156°C/W when mounted on a minimum pad of 2oz Cu on FR-4 board.

2. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2.0%.





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